

## Supporting Information

### **Thermally stable fishnet-like 1T-MoS<sub>2</sub>/CNTs heterostructures with improved electrode performance**

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### Density Functional Theory Calculations.

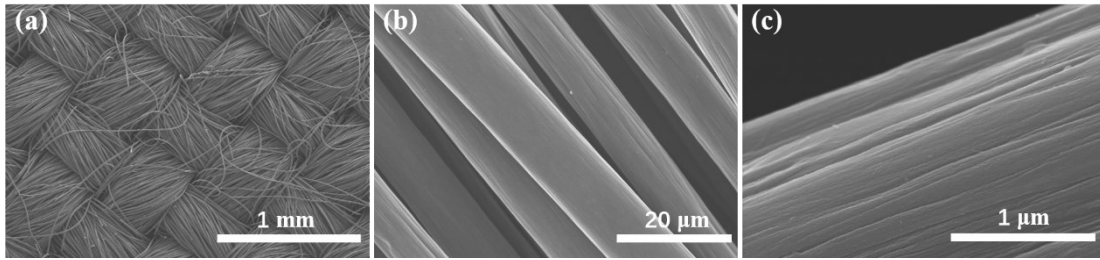
The calculations were performed in the framework of DFT with the CASTEP program in Materials Studio by Accelrys Inc.<sup>[1]</sup> The Perdew–Burke–Ernzerhof (PBE) functional within the generalized gradient approximation (GGA) was used to evaluate the nonlocal exchange correlation energy.<sup>[2]</sup> An ultrasoft pseudopotential was used for interactions between electrons and ions.<sup>[3]</sup> A cutoff energy of 421 eV and 3\*3\*1 k-point grid generated with the Monk-horst– Pack scheme were used. The Grimme method were used for DFT-D correction. A vacuum of 10 Å was inserted between neighboring cells along the c-axis to minimize interactions between cells. The atomic structures were optimized using the BFGS algorithm.<sup>[4]</sup> The convergence criteria were set to: (1) an energy tolerance of 1.0e<sup>-5</sup> eV per atom; (2) a force tolerance of 0.03 eV Å<sup>-1</sup>; (3) a max displacement tolerance of 0.001 Å; (4) a self-consistent field tolerance of 1.0e<sup>-5</sup> eV per atom. The transition state (TS) searches were performed at the same theoretical level with the complete linear synchronous transit/quadratic synchronous transit (LST/QST) method.<sup>[5-6]</sup> 3×3 MoS<sub>2</sub> and MoS<sub>2</sub>-Graphene with ether structures were adopted for TS searches calculation and the total energy was divided by 9 to obtain the activation energy per MoS<sub>2</sub> unit cell.

### Calculations method of specific capacity.

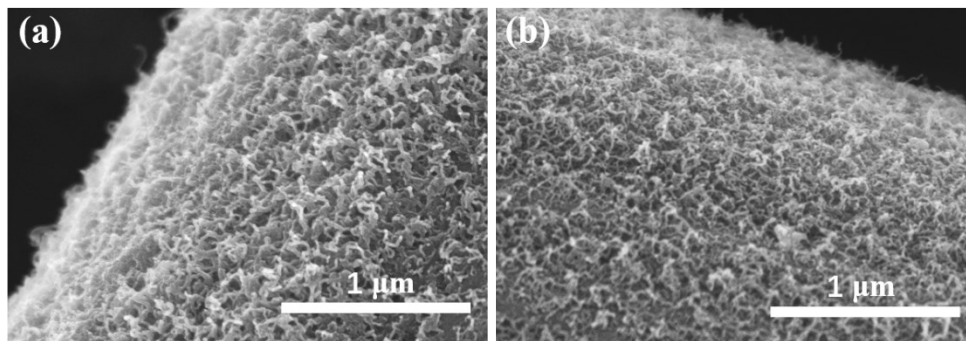
The specific capacity of 3D@1T-MoS<sub>2</sub> is calculated by removing the contribution of CNT-CFC matrix. Specifically, we calculate the specific capacity of 3D@1T-MoS<sub>2</sub> by using

$$SC_M = (AC_M - AC_C) / A_M$$

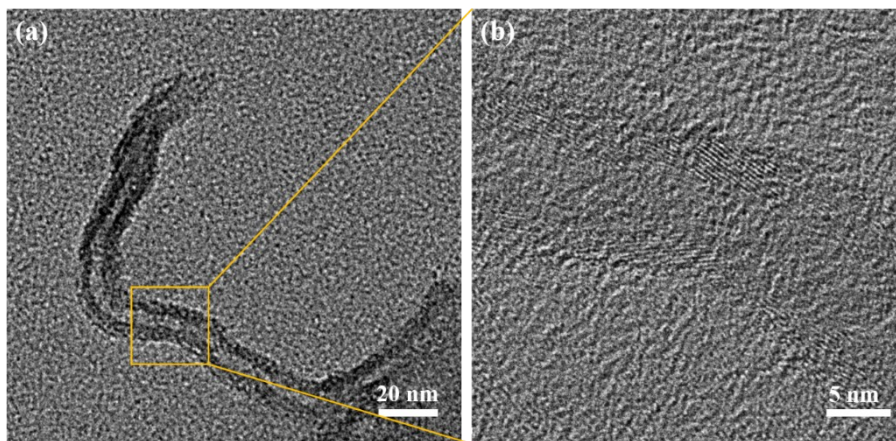
Where  $SC_M$  is the specific capacity of 3D@1T-MoS<sub>2</sub>,  $AC_M$  and  $AC_C$  are the average area capacity of 3D@1T-MoS<sub>2</sub> and CNT-CFC, respectively.  $A_M$  is the mass loading of MoS<sub>2</sub> on 3D@1T-MoS<sub>2</sub>. For example, the mass loading of MoS<sub>2</sub> on 3D@1T-MoS<sub>2</sub> is 1.00 mg cm<sup>-2</sup>, the average area capacity of 3D@1T-MoS<sub>2</sub> is 3.942 mAh cm<sup>-2</sup> at 0.1 mA cm<sup>-2</sup>, and the average area capacity of CNT-CFC is 2.947 mAh cm<sup>-2</sup> at 0.1 mA cm<sup>-2</sup>(Fig. 4c). So, the average specific capacity of 3D@1T-MoS<sub>2</sub> at 0.1 mA cm<sup>-2</sup> for LIBs is calculated as 995 mAh g<sup>-1</sup>. The specific capacity of 3D@1T-MoS<sub>2</sub>-700 is calculated in the same way (1.1 mg cm<sup>-2</sup>).



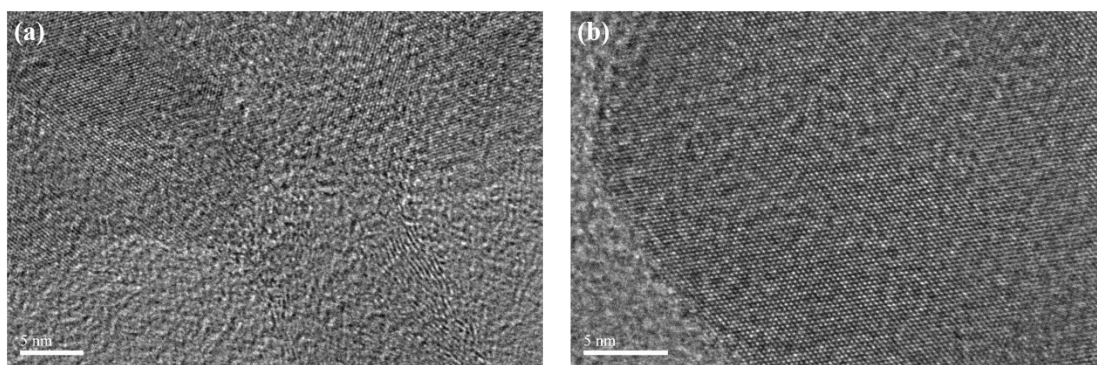
**Fig. S1** SEM images of annealed CFC with different magnification (a), (b) and (c).



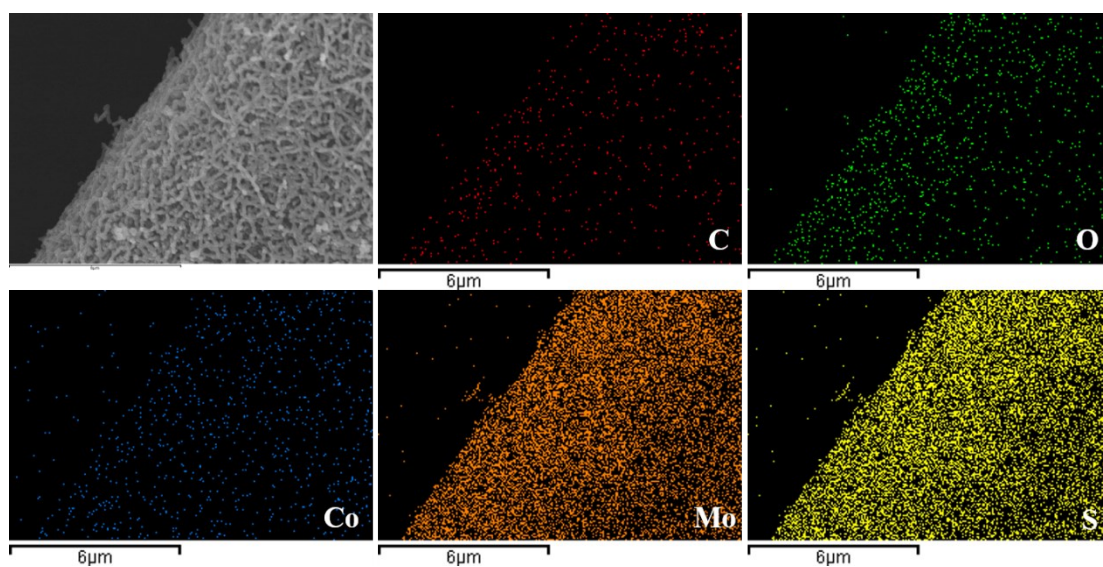
**Fig. S2** SEM images of CNT-CFC (a) before and (b) after calcined at 700 °C in an Ar atmosphere.



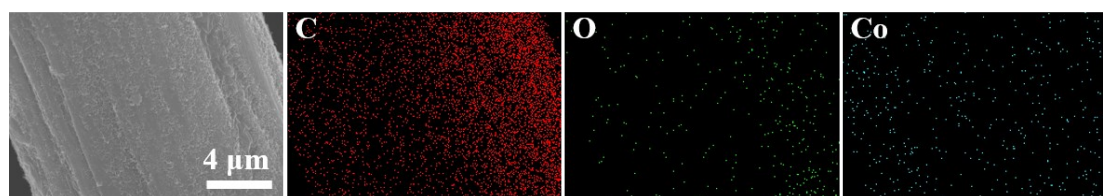
**Fig. S3** TEM and HR-TEM images of CNT-CFC.



**Fig. S4** HR-TEM images of 3D@1T-MoS<sub>2</sub>-700.

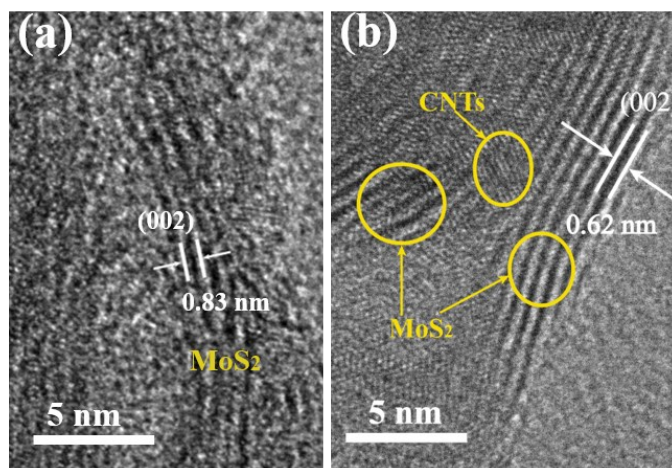


**Fig. S5** SEM image of 3D@1T-MoS<sub>2</sub> and corresponding elemental mapping images of C (red), O (green), Co (blue), Mo (orange) and S (yellow).

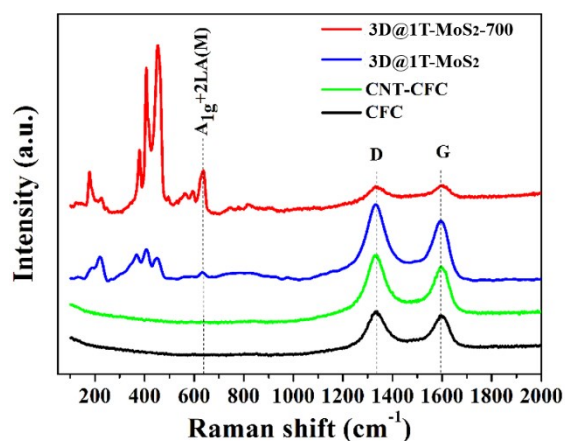


**Fig. S6** SEM image of CNT-CFC and corresponding elemental mapping images of C (red), O (green) and Co (blue).





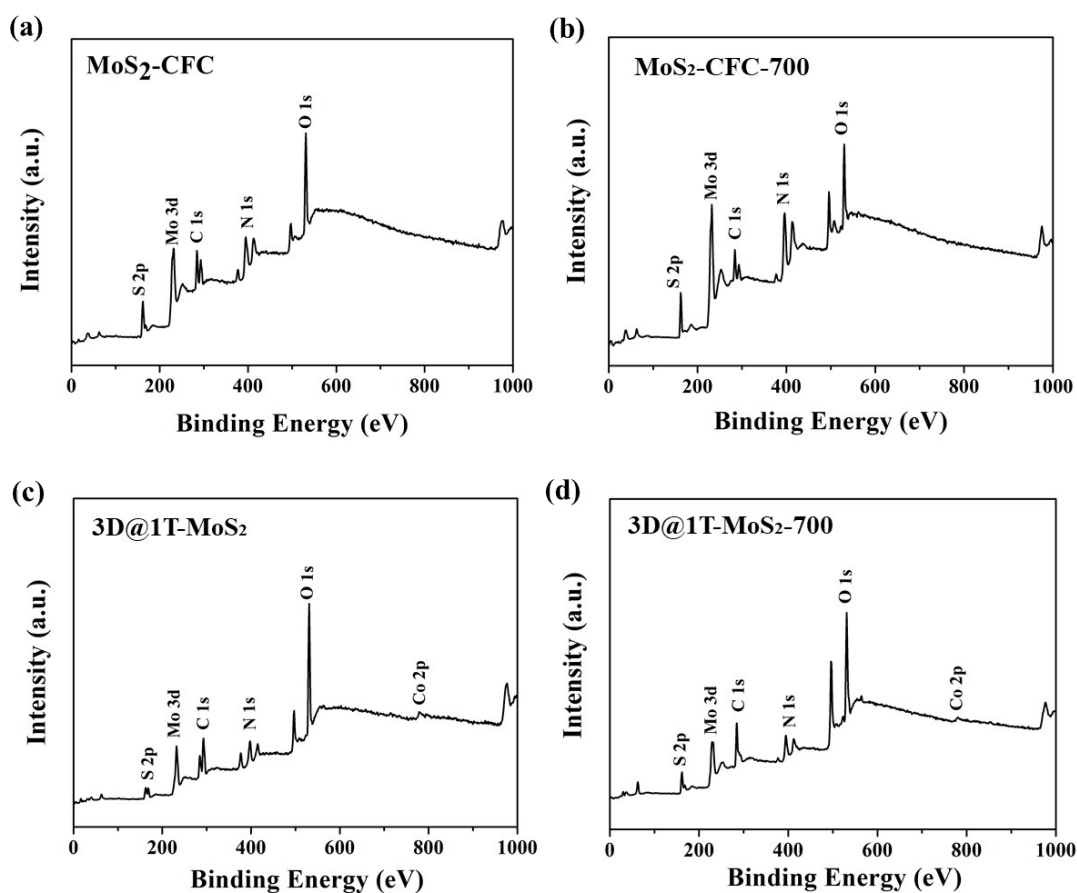
**Fig. S7** HR-TEM images of (a) 3D@1T-MoS<sub>2</sub> and (b) 3D@1T-MoS<sub>2</sub>-700.



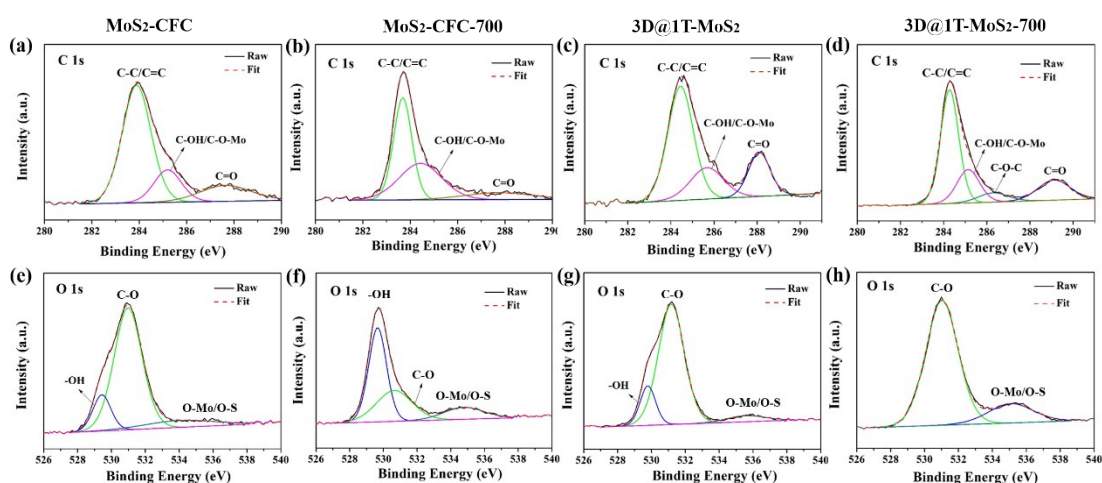
**Fig. S8** Raman spectra of CFC, CNT-CFC, 3D@1T-MoS<sub>2</sub> and 3D@1T-MoS<sub>2</sub>-700.

**Table S1** The relative fraction of 1T components of MoS<sub>2</sub> nanosheets with and without CNT as a composite, before and after 700 °C annealing in Ar atmosphere for 2 h, estimated by the deconvolution of Mo and S XPS peaks.

materials	all%		S%		Mo%	
	1T	2H	1T	2H	1T	2H
MoS <sub>2</sub> -CFC	51.01	48.99	53.21	46.79	48.68	51.32
MoS <sub>2</sub> -CFC-700	0.00	100.00	0.00	100.00	0.00	100.00
3D@1T-MoS <sub>2</sub>	38.20	61.80	51.27	48.73	26.87	73.13
3D@1T-MoS <sub>2</sub> -600	76.51	23.49	68.35	31.65	84.67	15.33
3D@1T-MoS <sub>2</sub> -700	62.12	37.88	56.25	43.75	67.76	32.24



**Fig. S9** Survey XPS spectrum of (a) MoS<sub>2</sub>-CFC, (b) MoS<sub>2</sub>-CFC-700, (c) 3D@1T-MoS<sub>2</sub> and (d) 3D@1T-MoS<sub>2</sub>-700.



**Fig. S10** High-resolution XPS C 1s and O 1s spectra of the four selected samples. Each band was deconvoluted following the literature.

Rate constant based on the Arrhenius-type equation

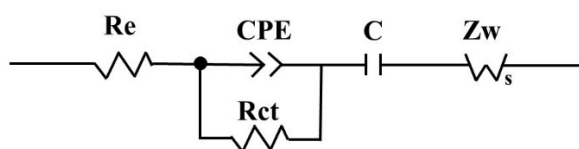
$$k = Ae^{-E_a/RT} \longrightarrow \frac{k_{MoS_2}}{k_{MoS_2/CNT}} = \frac{Ae^{-0.712/0.025}}{Ae^{-0.900/0.025}} \approx 1.8 \times 10^3$$

$$E_a = \Delta E * 1.6e^{-19} * 6.02e^{23} \text{ J} \cdot \text{mol}^{-1}$$

$$R = 8.314 \text{ J} \cdot \text{mol}^{-1} \text{K}^{-1}$$

$$T = 298.15 \text{ K}$$

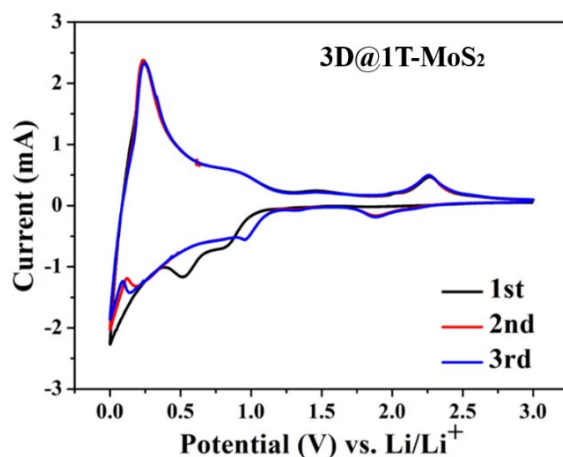
**Fig. S11** As based on the Arrhenius-type equation with the calculated activation energy difference, CNTs binding on MoS<sub>2</sub> slows down the phase transition about 1845 times.



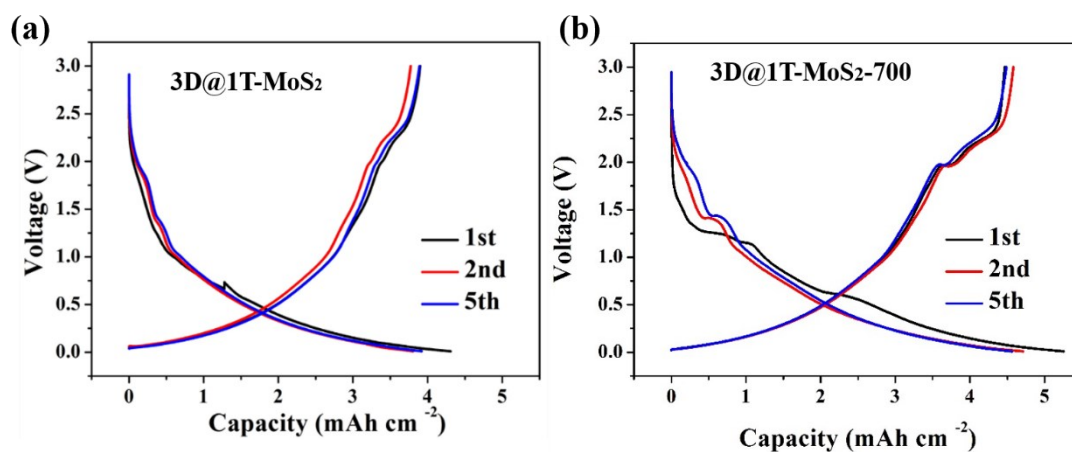
**Fig. S12** Equivalent circuit model to fit the Nyquist plots. Re is the resistance of electrolyte diffusion (the intercept of the semicircle at the imaginary axis); Rct is the charge-transfer resistance within the composites (the diameter of the semicircle); Zw is the Warburg-type resistance caused by ion diffusion in the electrode (the oblique inclined line in the low-frequency region).

**Table S2** Equivalent circuit parameters of CFC, CNT-CFC, MoS<sub>2</sub>-CFC, MoS<sub>2</sub>-CFC-700, 3D@1T-MoS<sub>2</sub> and 3D@1T-MoS<sub>2</sub>-700.

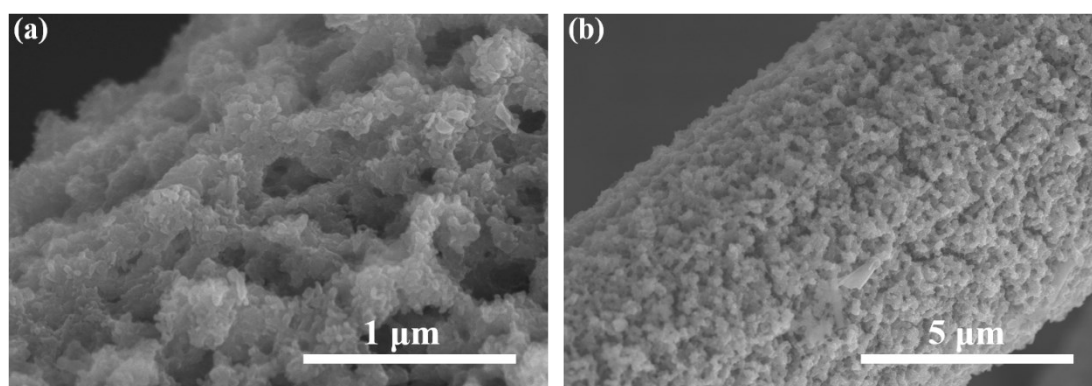
<i>Electrode</i>	<i>Re(Ω)</i>	<i>Rct(Ω)</i>
<i>CFC</i>	5.002	299.8
<i>CNT-CFC</i>	6.783	23.98
<i>MoS<sub>2</sub>-CFC</i>	10.14	8.032
<i>MoS<sub>2</sub>-CFC-700</i>	5.242	24.00
<i>3D@1T-MoS<sub>2</sub></i>	6.944	37.21
<i>3D@1T-MoS<sub>2</sub>-700</i>	2.261	15.52



**Fig. S13** CV curves of 3D@1T-MoS<sub>2</sub> electrodes at a scan rate of 0.1 mV s<sup>-1</sup> between 0.01 and 3.0 V.

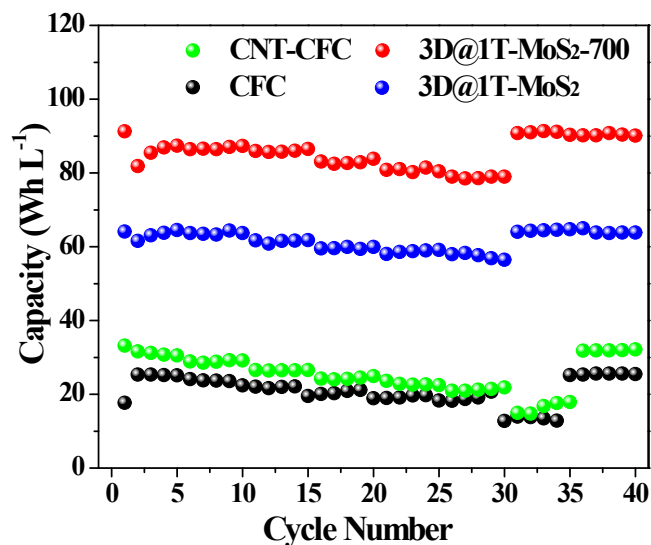


**Fig. S14** Discharge and charge voltage profiles of (a) 3D@1T-MoS<sub>2</sub> and (b) 3D@1T-MoS<sub>2</sub>-700 electrode at a current density of 0.1 mA cm<sup>-2</sup> for different cycles.

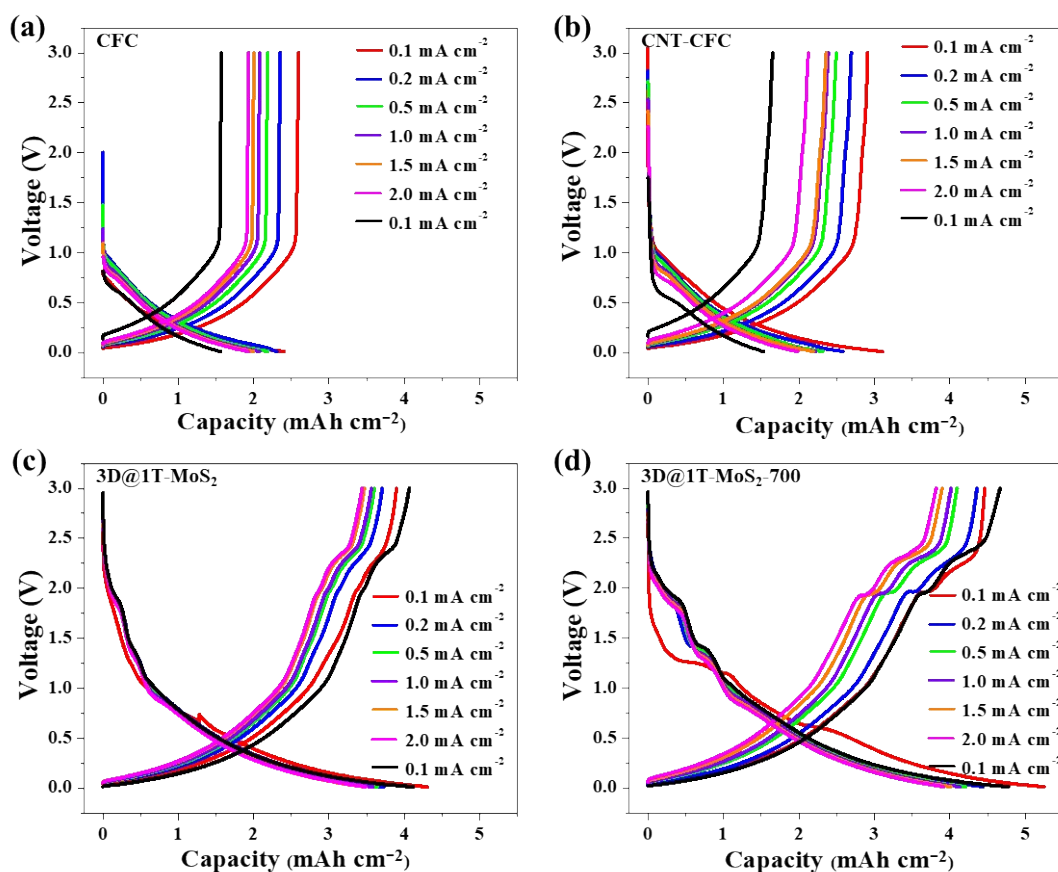


**Fig. S15** (a,b) SEM images of 3D@1T-MoS<sub>2</sub>-700 electrodes discharged to 0.01 V at current densities of 0.1 mA cm<sup>-2</sup> in the first cycle.

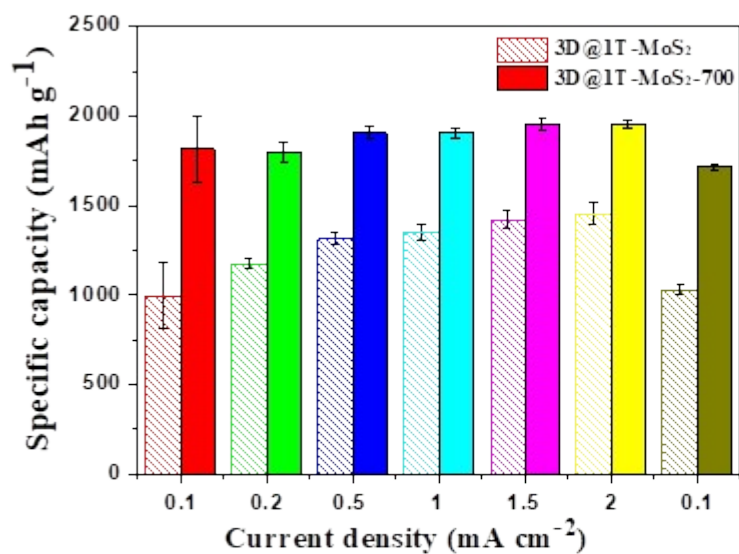




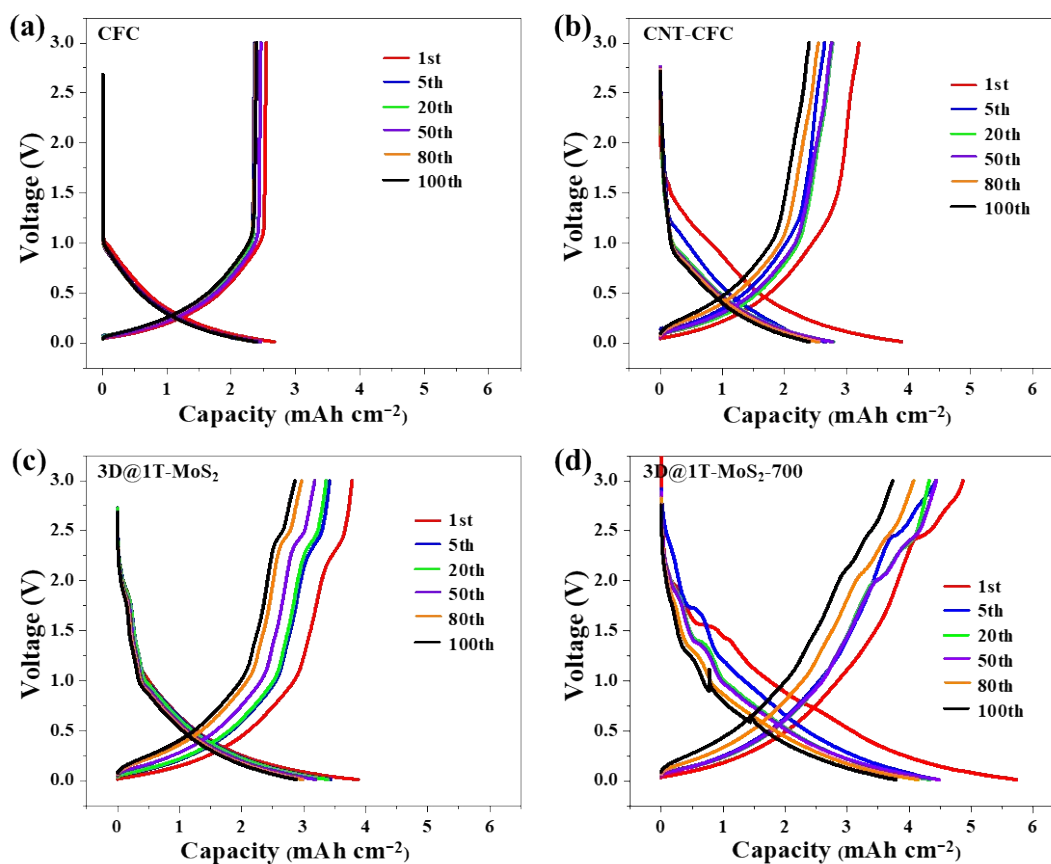
**Fig. S16** The volume energy density of the CFC, CNT-CFC, 3D@1T-MoS<sub>2</sub>, and 3D@1T-MoS<sub>2</sub>-700 electrodes at different current densities (The area of the electrode material is 1.13094 cm<sup>2</sup>. The thickness of the electrode material is 0.337±0.010 mm.).



**Fig. S17** The galvanostatic discharge and charge voltage profiles of (a) CFC, (b) CNT-CFC, (c) 3D@1T-MoS<sub>2</sub> and (d) 3D@1T-MoS<sub>2</sub>-700 electrode at different current densities.



**Fig. S18** The calculated specific capacity of 3D@1T-MoS<sub>2</sub> and 3D@1T-MoS<sub>2</sub>-700 for LIBs.



**Fig. S19** The galvanostatic discharge and charge voltage profiles of (a) CFC, (b) CNT-CFC, (c) 3D@1T-MoS<sub>2</sub> and (d) 3D@1T-MoS<sub>2</sub>-700 electrode at a current density of 0.5 mA cm<sup>-2</sup> for different cycles.

**Reference:**

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